



DPP – 4 (Semiconductor)

Video Solution on Website:- https://physicsaholics.com/home/courseDetails/63

Video Solution on YouTube:-

https://youtu.be/zyA86Uok2Ik

Written Solution on Website:- https://physicsaholics.com/note/notesDetalis/22

Q 1. An n-p-n transistor circuit is arranged as shown in fig. It is –



- (d) 100
- Q 3. In a common base connection, current amplification factor is 0.9. If the emitter current is 1mA, determine the value of base current.
 - (a) 0.1 mA
 - (b) 0.2 mA
 - (c) 0.4 mA
 - (d) 0.5 mA
- Q 4. For the common base circuit shown in Figure, determine I_C and V_{CB} . Assume the transistor to be of silicon.





- (a) 4.87 mA ,12.16 V (b) 3.27 mA ,11.16 V (c) 4.87 mA ,11.16 V (d) 3.27 mA ,12.16 V
- Q 5. For a transistor, $\beta = 45$ and voltage drop across $1k\Omega$ which is connected in the collector circuit is 1 volt. Find the base current for common emitter connection.

 I_C

(a) 0.022 mA (b) 0.011 mA (c) 0.033 mA (d) 0.044 mA A transistor is connected in common emitter (CE) configuration in which collector

- Q 6. A transistor is connected in common emitter (CE) configuration in which collector supply is 8 V and the voltage drop across resistance R_C connected in the collector circuit is 0.5 V. The value of $R_C = 800 \Omega$. If $\alpha = 0.96$, determine base current
 - (a) 0.026 mA (b) 0.011 mA
 - (c) 0.033 mA
 - (d) 0.044 mA

Q 7. Choose the correct option:



- (a) In circuit 1 lamp does not glow but in circuit 2 lamp glows
- (b) In circuit 1 as well as 2 lamp does not glow
- (c) In circuit 1 lamp glows but in 2 lamp does not glow
- (d) In both circuit lamp glows
- Q 8. Figure shows an n-p-n transistor. Choose the correct statement out of the following :







(a) Collector-base junction as well as emitter-base junction both are forward biased
(b) Collector-base junction as well as emitter-base junction both are reverse biased
(c) Collector-base junction is forward biased and emitter-base junction is reverse biased

(d) Collector-base junction is reverse-biased and emitter-base junction is forward biased

Q 9. In the junction transistor voltage amplifier circuit of figure, if $R_1 = 100 \text{ k} \Omega$, $R_2 = 1 \text{ k} \Omega$, $V_{ec} = 6.0 \text{ V}$ and $V_{BE} = 0.6 \text{ V}$, current gain = 60

↓ I_c

R.

- (a) $I_B = 54 \mu A$ (b) $I_C = 3.24 \text{ mA}$
- (c) the voltage across $R_2 = 3.24$ V
- (d) the voltage across the collector-emitter = 3.24

I_Bv

 R_1

Q 10. Output characteristic of n-p-n transistor in CE configuration is shown. From the characteristic curve determine the current gain at $V_{CE} = 1$ V –



- (d) 40
- Q 11. A transistor is connected in common emitter configuration .The collector emitter voltage is 8V and load resistance of 800 Ω is connected in the collector circuit. The voltage drop across the load resistance is 0.5V. If α be 0.96, what is the base current (a) 5 μ A





(b) 8 μ A
(c) 9.6 μA
(d) 26 μ A



Answer Key

Q.1) b	Q.2) b	Q.3) a	Q.4) a	Q.5) a
Q.6) a	Q.7) a	Q.8) d	Q.9) a,b,c	Q.10) a
Q.11) d				